



DLD101

LINEAR MODE CURRENT SINK LED DRIVER

Features

- Primarily Designed for Driving LED/s for Illumination, Signage and Backlighting Applications
- Ideally Suited for Linear Mode Constant Current Applications
- V_{BE} Referenced Current Sink Circuit
- Includes:
 - N-Channel Enhancement Mode MOSFET (Q1)
 - Base Accessible Pre-Biased Transistor (Q2)
- High Voltage Capable (50V)
- Small Form Factor Surface Mount Package
- High Dissipation Capability
- Low Thermal Resistance
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: DFN3030D-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 7
- Ordering Information: See Page 7
- Weight: 0.0172 grams (approximate)





Package Pin-Out Configuration



Typical Application Circuit for Linear Mode Current Sink LED Driver

Maximum Ratings: (Q1) @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Drain Source Voltage		V _{DSS}	100	V
Gate-Source Voltage		V _{GSS}	±20	V
Drain Current (Note 3)	T _A = 25°C T _A = 70°C	I _D	1.0 0.8	А
Drain Current (Note 3)	Pulsed	I _{DM}	3.0	А
Body-Diode Continuous Current (Note 3)		Is	1.0	А

Maximum Ratings: (Q2) @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage	V _{CC}	50	V
Input Voltage	V _{IN}	-5 to +30	V
Output Current (DC)	lo	100	mA

Notes: 1. No purposefully added lead.

2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.



Thermal Characteristics – Total Device

Characteristic	Symbol	Value	Unit
Power Dissipation $@T_A = 25^{\circ}C$	PD	0.7 (Note 3) 0.9 (Note 4) 1.4 (Note 5)	w
Thermal Resistance Junction to Ambient Air $@T_A = 25^{\circ}C$	R _{θJA}	178 (Note 3) 138 (Note 4) 123 (Note 5)	°C/W
Thermal Resistance Junction to Case Air $@T_A = 25^{\circ}C$	R _{θJC}	30 (Note 3) 35.5 (Note 4) 35.7 (Note 5)	°C/W
Operating and Storage Temperature Range	TI, TSTG	-55 to +150	°C

Notes:

Part mounted on FR-4 substrate PC board, with minimum recommended pad layout (see page 6).
Part mounted on FR-4 substrate PC board, 2oz Copper with 6 mm2 Cu Area, MOSFET element activated.
Part mounted on FR-4 substrate PC board, 2oz Copper with 35 mm2 Cu Area, MOSFET element activated.

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition			
OFF CHARACTERISTICS (Note 6)									
Drain-Source Breakdown Voltage	BV _{DSS}	100	_		V	$V_{GS} = 0V, I_D = 250 \mu A$			
Zero Gate Voltage Drain Current	IDSS	_		1	μΑ	$V_{DS} = 60V, V_{GS} = 0V$			
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$			
ON CHARACTERISTICS (Note 6)									
Gate Threshold Voltage	V _{GS(th)}	2.0		4.1	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$			
Static Drain Source On Registered	P		_	0.85	0	$V_{GS} = 10V, I_D = 1.5A$			
	RDS (ON)		_	0.99	52	$V_{GS} = 6V, I_D = 1A$			
Forward Transconductance	g fs	_	0.9		S	$V_{DS} = 15V, I_D = 1A$			
Diode Forward Voltage	V _{SD}		0.89	1.1	V	$V_{GS} = 0V, I_{S} = 1.5A$			
DYNAMIC CHARACTERISTICS									
Input Capacitance	Ciss		129		pF				
Output Capacitance	Coss	—	14		pF	$v_{DS} = 50V, v_{GS} = 0V$ f = 1.0MHz			
Reverse Transfer Capacitance	C _{rss}		8	_	pF				
SWITCHING CHARACTERISTICS									
Total Gate Charge	Qg	_	3.4						
Gate-Source Charge	Q _{gs}		0.9	_	nC	$V_{DS} = 50V, V_{GS} = 10V, I_D = 1A$			
Gate-Drain Charge	Q _{gd}	_	1	_					
Turn-On Delay Time	t _{d(on)}		7.9	_					
Rise Time	tr		11.4	_	n 0	$V_{GS} = 50V, V_{DS} = 10V,$			
Turn-Off Delay Time	t _{d(off)}		14.3		115	$I_D = 1A, R_G \approx 6\Omega$			
Fall Time	t _f		9.6	_					

Electrical Characteristics: (Q2) @T_A = 25°C unless otherwise specified

Characteristic (Note 6)	Symbol	Min	Тур	Max	Unit	Test Condition
	V _{I(off)}	0.4	-	-	V	$V_{CC} = 5V, I_{O} = 100 \mu A$
niput voltage	V _{I(on)}	-	-	1.5	V	$V_{CC} = 0.3V, I_{O} = 5mA$
Output Voltage	V _{O(on)}	-	0.05	0.3	V	$I_0/I_1 = 5mA/0.25mA$
Output Current	I _{O(off)}	-	-	0.5	μA	$V_{CC} = 50V, V_I = 0V$
DC Current Gain	G ₁	80	-	-	-	$V_0 = 5V, I_0 = 10mA$
Input Resistance	R ₁	3.2	4.7	6.2	kΩ	-
Resistance Ratio	R ₂ /R ₁	8	10	12	-	-
Transition Frequency	f⊤	-	260	-	MHz	$V_{CE} = 10V$, $I_E = 5mA$, f = 100MHz

6. Short duration pulse test used to minimize self-heating effect. Notes:











NEW PRODUCT



0∟ -50

-25

0

0.6

0.3

V_{GS} = 10V

 $I_{\rm D} = 1.5 {\rm A}$

50

T_A, AMBIENT TEMPERATURE (°C)

75

100

125 150

25

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1,000 NUCLEAR DECISION OF TA = 150°C TA = 150°C TA = 150°C TA = 25°C TA

DLD101





NEW PRODUCT

DLD101 Document number: DS32007 Rev. 7 - 2 Downloaded from Elcodis.com electronic components distributor



Typical Application Circuit



Fig. 12 Typical Application Circuit for Linear Mode Current Sink LED Driver

The DLD101 has been designed primarily for solid state lighting applications, to be used as a current sink circuit solution for LEDs. It features a N-channel MOSFET capable of 1A drive current and a prebiased NPN transistor (which allows direct connection to the base, or via a series base resistor).

Figure 12 shows a typical application circuit diagram for driving an LED or string of LEDs. Note that the pre-biased transistor (Q2) has the option of bypassing the series base resistor by connecting directly to pin 7. The N-MOSFET (Q1) is configured as a V_{BE} referenced current sink and is biased on by R_C. The current passed through the LED string, MOSFET and source resistor, develops a voltage across R_S that provides a bias to the NPN transistor. Consideration of the expected linear mode power dissipation must be factored into the design, with respect to the DLD101's thermal resistance.

$$\begin{split} V_{DS} &= V_{CC} - V_{F \; LED \; String} - V_{RS} \\ P_{Q1} &= V_{DS} \;^* \; I_{LED \; String} \end{split}$$

PWM dimming functionality can be effected by either driving the NPN base via an additional resistor (thereby overriding the feedback from R_S) or by pulling the gate of the MOSFET down by direct connection. The PWM control pulse stream can be provided by a micro-controller or simple 555 based circuitry.

Ordering Information (Note 7)

Part Number Case		Packaging
DLD101-7	DFN3030D-8	3000/Tape & Reel

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



L101 = Product marking code YYWW = Date code marking YY = Last digit of year (ex: 10 for 2010) WW = Week code (01 to 53)







Package Outline Dimensions



DFN3030D-8							
Dim	Min	Max	Тур	Dim	Min	Max	Тур
Α	0.570	0.630	0.600	е	-	-	0.650
A1	0	0.050	0.020	Е	2.950	3.075	3.000
A3	-	-	0.150	E1	1.800	2.000	1.900
b	0.290	0.390	0.340	E2	0.290	0.490	0.390
D	2.950	3.075	3.000	E3	0.175	0.375	0.275
D1	2.175	2.375	2.275	L	0.300	0.40	0.350
D2	0.980	1.180	1.080	Z	-	-	0.355
D3 0.105 0.305 0.205							
All Dimensions in mm							

Suggested Pad Layout



Dimensions	Value (in mm)	Dimensions	Value (in mm)
C	0.650	X2	0.220
G	0.150	X3	0.375
G1	0.950	X4	1.080
G2	0.270	X5	0.150
G3	0.135	Y	2.600
G4	1.350	Y1	1.900
G5	0.925	Y2	0.150
G6	1.350	Y3	0.390
X	0.440	Y4	0.815
X1	0.210	Y5	0.550



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